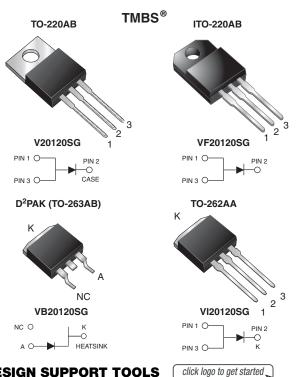
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High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.54 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS



PRIMARY CHARACTERISTICS					
I _{F(AV)}	20 A				
V_{RRM}	120 V				
I _{FSM}	150 A				
V_F at $I_F = 20 A$	0.78 V				
T _J max.	150 °C				
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA				
Circuit configuration	Single				

FEATURES

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

· High efficiency operation

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

RoHS

• Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D²PAK (TO-263AB), TO-262AA

and

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V20120SG	VF20120SG	VB20120SG	VI20120SG	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	120					
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	20					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	150				Α	
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH	E _{AS}	80				mJ	
Peak repetitive reverse current at $t_p = 2 \mu s$, 1 kHz, $T_J = 38 ^{\circ}C \pm 2 ^{\circ}C$	I _{RRM}	0.5			Α		
Voltage rate of change (rated V _R)	dV/dt	10 000			V		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150				°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	120 (minimum)	-	V	
Instantaneous forward voltage	I _F = 5 A	T _A = 25 °C	- V _F ⁽¹⁾	0.62	=	V	
	I _F = 10 A			0.81	=		
	I _F = 20 A			1.20	1.33		
	I _F = 5 A	T _A = 125 °C		0.54	=		
	I _F = 10 A			0.65	=		
	I _F = 20 A			0.78	0.88		
Reverse current	V _R = 90 V	T _A = 25 °C	1 (2)	10	=	μΑ	
		T _A = 125 °C		7	=	mA	
	V _R = 120 V	T _A = 25 °C	I _R ⁽²⁾	-	250	μΑ	
		T _A = 125 °C		12	25	mA	

Notes

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V20120SG	VF20120SG	VB20120SG	VI20120SG	UNIT	
Typical thermal resistance	$R_{\theta JC}$	2.2	4.2	2.2	2.2	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V20120SG-E3/4W	1.88	4W	50/tube	Tube		
ITO-220AB	VF20120SG-E3/4W	1.75	4W	50/tube	Tube		
TO-263AB	VB20120SG-E3/4W	1.38	4W	50/tube	Tube		
TO-263AB	VB20120SG-E3/8W	1.38	8W	800/reel	Tape and reel		
TO-262AA	VI20120SG-E3/4W	1.45	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

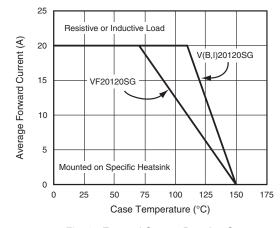


Fig. 1 - Forward Current Derating Curve

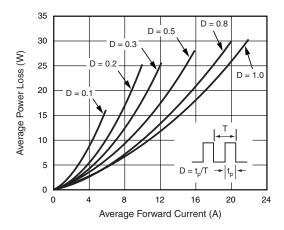


Fig. 2 - Forward Power Loss Characteristics

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

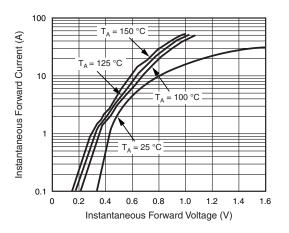


Fig. 3 - Typical Instantaneous Forward Characteristics

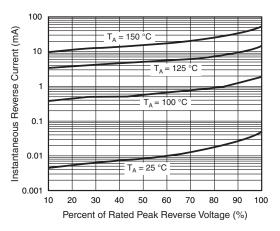


Fig. 4 - Typical Reverse Characteristics

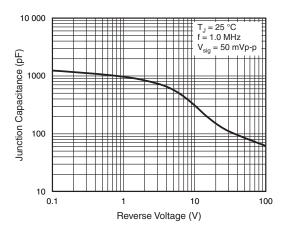


Fig. 5 - Typical Junction Capacitance

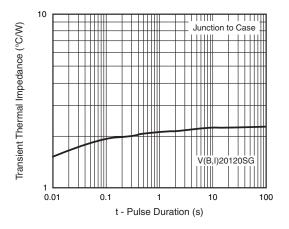


Fig. 6 - Typical Transient Thermal Impedance

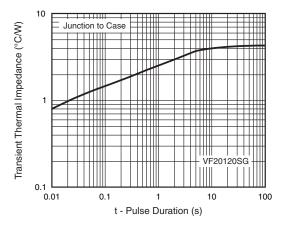
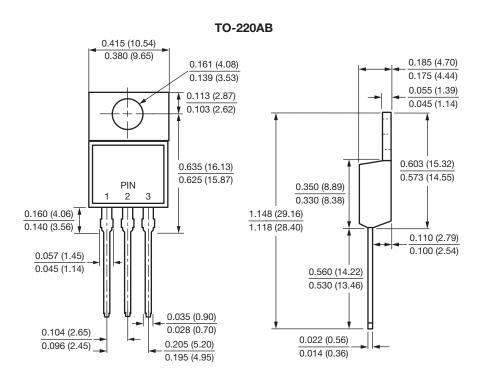


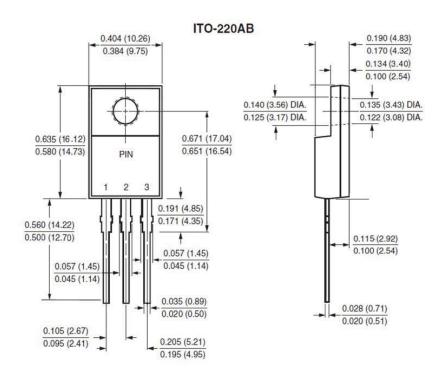
Fig. 7 - Typical Transient Thermal Impedance

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

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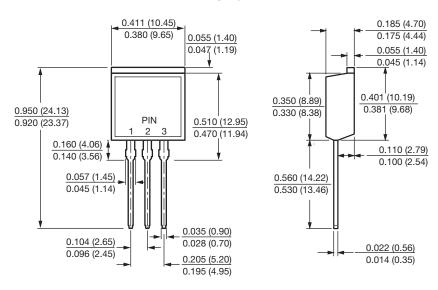




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TO-262AA



D²PAK (TO-263AB) 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.045 (1.14) 0.245 (6.22) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) NC Κ 0.591 (15.00) -0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout 0.42 (10.66) MIN. 0.33 (8.38) MIN. 0.670 (17.02) 0.591 (15.00) 0.15 (3.81) MIN.

0.08 (2.032) MIN.

0.105 (2.67)

0.095 (2.41)



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